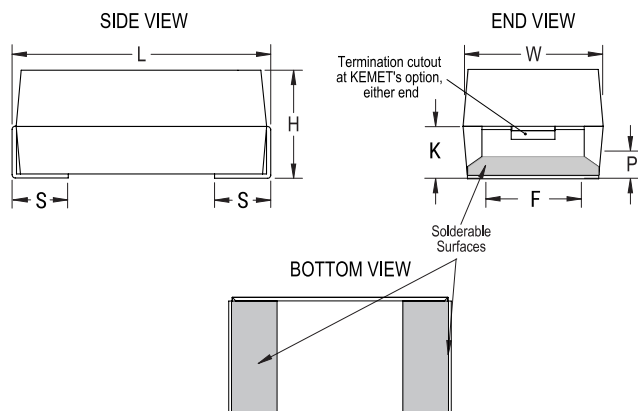


CWR09FB475KB

Aliases (T409D475K010BB)

T409 CWR09, Tantalum, MnO2 Tantalum, Military/High Reliability, 4.7 uF, 10%, 10 VDC, SMD, MnO2, Molded, Military Equivalent, B (0.1%/1000 Hrs), 4.5 Ohms, 3825, 1.65mm



Click [here](#) for the 3D model.

General Information

Series	T409 CWR09
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Military Equivalent
RoHS	Yes
Termination	Gold
Qualifications	MIL-PRF-55365/4, CWR09 Style
AEC-Q200	No
Typical Component Weight	264.12 mg
Notes	Note: When Option C Is Selected For Lead Material, Add An Additional 0.38mm To The Tolerances For "L", "W", "H", "K", "F" And "S".
MSL	1

Specifications

Capacitance	4.7 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	4.5 Ohms (100kHz 25C)
Ripple Current	133 mA (rms, 100kHz 25C)
Leakage Current	1 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

Dimensions

Footprint	3825
L	3.81mm +/-0.38mm
W	2.54mm +/-0.38mm
H	1.27mm +/-0.38mm
S	0.76mm +0.25/-0.13mm
F	2.41mm +0.13/-0.25mm
K	0.76mm MIN
P	0.38mm MIN

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2500

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